

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Franz Hofmann et al.

Application No.: 10/768,971

Confirmation No.: 4544

Filed: January 30, 2004

Art Unit: 2815

For: Fin field-effect transistor and method for
producing a fin field effect-transistor

Examiner: E. J. Wojciechowicz

AMENDMENT AFTER FINAL ACTION UNDER 37 C.F.R. 1.116

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated March 23, 2006, the following Remarks are respectfully submitted.

Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 8 of this paper.